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PATENT Docket No 150,00880105

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):	Derderian et al.	)	Group Art Unit:	2818
Serial No.: Confirmation	10/042,025 No., 5745	) ) )	Examiner:	Dang, P.
Filed:	25 October 2001	)		
For:	METHODS FOR FORMING ROUGH RUTHENIUM-CONTAINING LAYERS AND STRUCTURES/METHODS USING SAME			

## RESPONSE TO RESTRICTION REQUIREMENT

Assistant Commissioner for Patents

Washington, D.C. 20231

Dear Sir:

In response to the Restriction Requirement mailed 11 September 2002, Applicants elect, without traverse, Group I (claims 30-40), drawn to conductive structures. Applicants' Representatives reserve the right to pursue examination of the non-elected claims in continuation or divisional applications.

The Examiner is invited to contact Applicants' Representatives, at the below-listed telephone number, if there are any questions regarding this Response or if prosecution of this application may be assisted thereby.

The undersigned hereby certifies hat this paper is being transmitted by facsimite in accordance with 37 C.F.R. § 1.6(a) to the Parent and Trademark Office, addressed to Assistant Commissioner for Patents, Washington, D.C. 20231, on this day of September, 2002, at 10:35 AM (Central Time).

25 Sept 2012 Date Respectfully submitted for Micron Technology, Inc.

By Mueting, Raasch & Gebhardt, P.A. P.O. Box 581415 Minneapolis, MN 55458-1415 Phone: (612)305-1220 Facsimile: (612)305-1228

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FATENT INVOENTIGE

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